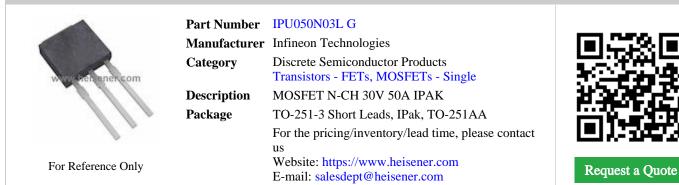


IPU050N03L G

IPU050N03L G Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPU050N03L G Specifications

Manufacturer Part Number	IPU050N03L G
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-251-3 Short Leads, IPak, TO-251AA
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	50A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	31nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3200pF @ 15V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	68W (Tc)
Rds On (Max) @ Id, Vgs	5 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO251-3
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
	Report errors

IPU050N03L G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPU050N03L G Payment Methods



IPU050N03L G Shipping Methods



If you have any question about IPU050N03L G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com